MOTOROLAN14CL供应商 SEMICONDUCTOR TECHNICAL DATA

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by MGP20N14CL/D

Product Preview MGP20N14CL **SMARTDISCRETES**TM **Internally Clamped, N-Channel** IGBT **20 AMPERES** This Logic Level Insulated Gate Bipolar Transistor (IGBT) VOLTAGE CLAMPED features Gate-Emitter ESD protection, Gate-Collector overvoltage N-CHANNEL IGBT protection from SMARTDISCRETES™ monolithic circuitry for V_{ce(on)} = 1.9 VOLTS usage as an Ignition Coil Driver. 135 VOLTS (CLAMPED) Temperature Compensated Gate–Drain Clamp Limits Stress Applied to Load Integrated ESD Diode Protection TMOS Low Threshold Voltage to Interface Power Loads to Logic or С Microprocessors Low Saturation Voltage • High Pulsed Current Capability CASE 221A-06, Style 9 δ TO-220AB F

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

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Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCES	CLAMPED	Vdc	
Collector–Gate Voltage	VCGR	CLAMPED	Vdc	
Gate-Emitter Voltage	VGE	CLAMPED	Vdc	
Collector Current — Continuous @ $T_C = 25^{\circ}C$ — Single Pulsed ($t_p = \pm 10 \ \mu s$)	IC ICM	20 60	Adc Apk	
Total Power Dissipation @ T _C = 25°C (TO-220) Derate Above 25°C	PD	150 1.0	Watts W/°C	
Operating and Storage Temperature Range	TJ, Tstg	-55 to 175	°C	
Single Pulse Collector–Emitter Avalanche Energy @ Starting $T_J = 25^{\circ}C$ (V _{CC} = 80 V, V _{GE} = 5 V, Peak I _L = 10 A, L = 10 mH)	EAS	500	mJ	
THERMAL CHARACTERISTICS	a free free free free free free free fre			

Thermal Resistance — Junction to Case – (TO–220) — Junction to Ambient	R _{θJC} R _{θJA}	1.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	тլ	275	°C
Mounting Torque, 6–32 or M3 screw	10 lbf∙in (1.13 N∙m)		

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ELECTRICAL CHARACTERISTICS ($(T_{C} = 25^{\circ}C \text{ unless otherwise noted})$
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Ch	aracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•		
Clamp Voltage (I _{Clamp} = 10 mA, T _J = -40 to	150°C)	BVCES	135			Vdc
Zero Gate Voltage Collector Curr ($V_{CE} = 100 \text{ V}, V_{GE} = 0 \text{ V}$) ($V_{CE} = 100 \text{ V}, V_{GE} = 0 \text{ V}, T_{J} = 0 \text{ V}$		ICES			10 100	μΑ
Gate-Emitter Clamp Voltage (IG	= 1 mA)	BVGES	10			Vdc
Gate-Emitter Leakage Current ($V_{GE} = \pm 5 \text{ V}, \text{ V}_{CE} = 0 \text{ V}$	IGES	—	-	1.0	μA
ON CHARACTERISTICS (1)		•	•	•		
Gate Threshold Voltage (V _{CE} = V _{GE} , I _C = 1 mA) Threshold Temperature Coeffic	cient (Negative)	VCE(th)	1.0	1.5 4.4	2.0	V mV/°C
Collector–Emitter On–Voltage (V _{GE} = 5 V, I _C = 10 A) (V _{GE} = 5 V, I _C = 10 Adc, T _J =	175°C)	VCE(on)			1.9 1.8	V
Forward Transconductance (VC	$= > 15 \text{ V}, \text{ I}_{\text{C}} = 10 \text{ A})$	9fs	8.0	15	—	Mhos
DYNAMIC CHARACTERISTICS		•	•	•		
Input Capacitance		C _{iss}	-	430	600	pF
Output Capacitance	(V _{CE} = 25 Vdc, V _{GE} = 0 Vdc, f = 1.0 MHz)	C _{OSS}	-	182	250	
Transfer Capacitance		C _{rss}	-	48	100	
SWITCHING CHARACTERISTICS	; 5 (1)					
Turn–On Delay Time		^t d(on)	—	TBD	TBD	ns
Rise Time	$(V_{CC} = 68 \text{ V}, I_C = 20 \text{ A}, V_{GE} = 5 \text{ V}, R_G = 9.1 \Omega)$	t _r	-	TBD	TBD	
Turn–Off Delay Time		^t d(off)	_	TBD	TBD	
Fall Time		tf	—	TBD	TBD	
Total Gate Charge		Qg	_	14	20	nC
Gate-Emitter Charge	(V _{CC} = 108 V, I _C = 20 A, V _{GE} = 5 V)	Qgs	-	3.0	—	1
Gate-Collector Charge		Q _{gd}	<u> </u>	6.0	_	

(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

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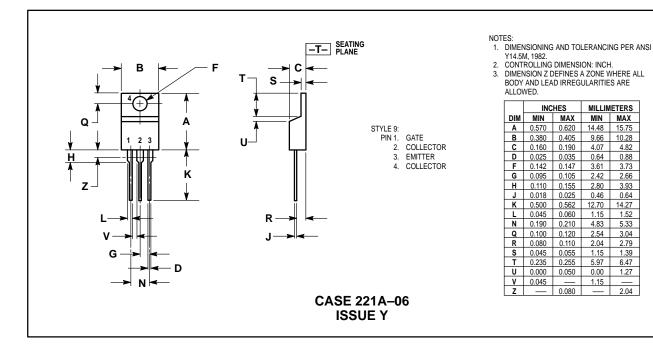
9.66 10.28

<u>2.79</u> <u>1.15</u> <u>1.39</u> <u>5.97</u> <u>6.47</u> <u>0.00</u> <u>1.27</u> <u>1.15</u>

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1.15





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